

Revision 0.50

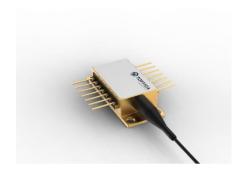
2025-01-21

## **SINGLE FREQUENCY LASER External Cavity Diode Laser**



	Information

Product	Application
780 nm mini-ECL Laser	Spectroscopy (Rb D2 line)
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	Quantum Technology
with integrated μ-Isolator and PM Fiber	



### Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts		-40		85
Operational Temperature at Case	$T_C$	°C	-40		85
Operational Temperature at Chip	$T_{chip}$	°C	-5		50
Forward Current	I <sub>F</sub>	mA			200
Reverse Voltage	$V_{R}$	V			2
Output Power	$P_{opt}$	mW			30
TEC Current	I <sub>TEC</sub>	Α			1.8
TEC Voltage	$V_{TEC}$	V			3.2

#### Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

### Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T <sub>case</sub>	°C	-20		65
Operational Temperature at Chip	$T_{chip}$	°C	0		45
Forward Current	I <sub>F</sub>	mA			180
Output Power	$P_{opt}$	mW	5		25

Measurement Conditions / Comments				
measured by integrated Thermistor				

#### Characteristics = 25° C at BOL

Target Wavelength $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Parameter	Symbol	Unit	min	typ	max
Linewidth $\Delta\lambda$ MHz 0.1 0.3 Mode-hop free Tuning Range $\Delta\lambda_{tune}$ pm 15 Output Power $P_{opt}$ mW 25 Sidemode Suppression Ratio	Center Wavelength	$\lambda_{C}$	nm	779	780	781
Mode-hop free Tuning Range	Target Wavelength	$\lambda_{\mathrm{T}}$	nm		780.24	
Output Power     Popt of the	Linewidth	Δλ	MHz		0.1	0.3
Sidemode Suppression Ratio SMSR dB 30 45	Mode-hop free Tuning Range	$\Delta \lambda_{tune}$	pm		15	
·	Output Power	$P_{opt}$	mW			25
Temp Coefficient of Wavelength d\(\lambda\) / dT nm/K 0.008	Sidemode Suppression Ratio	SMSR	dB	30	45	
Tomp. Coomoration travolongan	Temp. Coefficient of Wavelength	$d\lambda/dT$	nm/K		0.008	
Current Coefficient of Wavelength dλ / dl nm/mA 0.001	Current Coefficient of Wavelength	dλ / dl	nm/mA		0.001	

Measurement Conditions / Comments
reached within TLD = 0° C 45° C
measured in the time scale of 1 ms
By current tuning, at target wavelength
Popt = 25 mW

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Characteristics	= 25° C at BOL	
Parameter	Symbol Unit min	typ max
Laser Current	I <sub>LD</sub> mA	180
Slope Efficiency	η mW/mA	0.2
Threshold Current	I <sub>th</sub> mA	60
Polarization Extinction Ratio	PER dB	20

Measurement Conditions / Comments
Popt = 25 mW

Monitor Diode			
Parameter	Symbol Unit min	tvp	max
Monitor Detector Responsivity	I <sub>mon</sub> / P <sub>or</sub> μA/mW	10	- Trick

Measurement Conditions / Comments
5 V

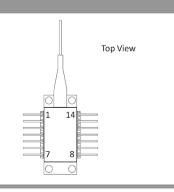
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Parameter	Symbol	Unit	min	typ	max
Current	I <sub>TEC</sub>	Α		0.4	
Voltage	$U_TEC$	V		1.5	
Power Dissipation (total loss at case)	P <sub>loss</sub>	W		0.5	
Temperature Difference	ΔΤ	K			50

Measurement Conditions / Comments
Popt = 25 mW, ΔT = 20 K
Popt = 25 mW, ΔT = 20 K
Popt = 25 mW, ΔT = 20 K
Popt = 25 mW, ΔT =  Tcase - TLD

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	Α		1.	.1293 x 10	3
Steinhart & Hart Coefficient B	В		2.	3410 x 10	<b>-</b> 4
Steinhart & Hart Coefficient C	С		8.	.7755 x 10	-8

Measurement Conditions / Comments
Tchip = 25° C
$R_1/R_2 = e^{\beta}(1/T_1 - 1/T_2)$ at Tchip = 0° 50° C
$1/T = A + B(\ln R) + C(\ln R)^3$
T: Temperature in Kelvin
R: resistance at T in $\Omega$

Pin Assignment	
4 7	44 7
1 Thermoelectric Cooler (+)	14 Thermoelectric Cooler (-)
2 Thermistor	13 Case
3 Photo Diode Anode	12 not connected
4 Photo Diode Cathode	11 Laser Diode Cathode
5 Thermistor	10 Laser Diode Anode
6 not connected	9 not connected
7 not connected	8 not connected



Thermistor (Standard NTC Type)

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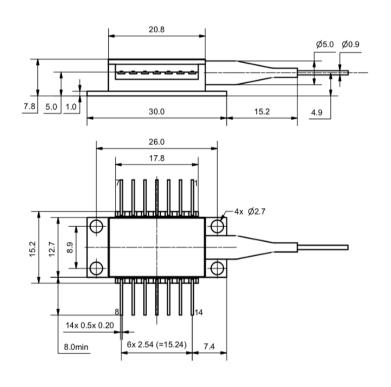
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## **SINGLE FREQUENCY LASER External Cavity Diode Laser**

### Package Drawings





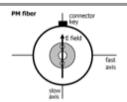
\* For properties of fiber pigtail and connector type please see P/N specification sheet

AIZ-16-0222-1415

### Fiber and Connector Type (Output)

PM Fiber	900 / 125 / 5.5 μm, UV/Polyester-elastomer Coating (I = 1 +/-0.1 m)
Connector	FC/APC (narrow key / 2mm)

### Measurement Conditions / Comments



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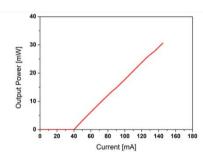
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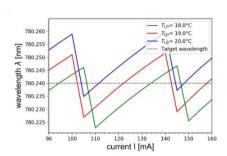
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# **SINGLE FREQUENCY LASER External Cavity Diode Laser**

#### Typical Measurement Results





#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.





A laser diode is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.



INVISIBLE LASER RADIATION

AVOID EYE OR SKIN EXPOSUR
TO DIRECT OR SCATTERED RADIATION CLASS
4 LASER PRODUCT

WAVELENGTH 780 nm

MAX. OUTPUT POWER 30 mW

IEC-60825-1

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.



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Complies with 21 CFR 1040.10 and 1040.40

Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

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